



SSC8644GS1

N and P-Channel Enhancement Mode Power MOSFET

➤ Features

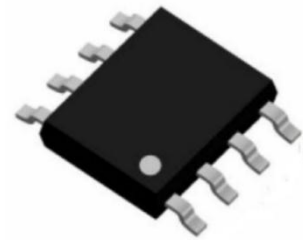
N-Channel

V_{DS}	V_{GS}	$R_{DS(ON)}$ Typ.	I_D
40V	$\pm 20V$	21m Ω @10V	8A
		27m Ω @4.5V	

P-Channel

V_{DS}	V_{GS}	$R_{DS(ON)}$ Typ.	I_D
-40V	$\pm 20V$	60m Ω @-10V	-4.7A
		70m Ω @-4.5V	

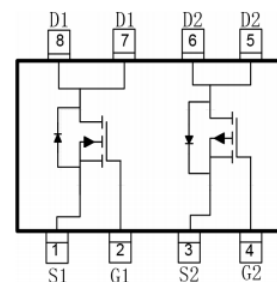
➤ Pin configuration



SOP-8

➤ Description

The SSC8644GS1 uses advanced trench technology to provide excellent $R_{DS(ON)}$ and low gate charge. The complementary MOSFETs may be used to form a level shifted high side switch, and for a host of other applications.



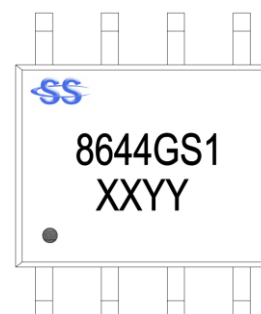
Pin Configuration (Top View)

➤ Applications

- PWM Applications
- Load Switch
- DC-DC Converters
- Wireless Chargers

➤ Ordering Information

Device	Package	Shipping
SSC8644GS1	SOP-8	4000/Reel



Marking (Top View)



➤ **Absolute Maximum Ratings ($T_A=25^{\circ}\text{C}$ unless otherwise noted)**

Parameter	Symbol	N-Channel	P-Channel	Unit
Drain-to-Source Voltage	V_{DSS}	40	-40	V
Gate-to-Source Voltage	V_{GSS}	± 20	± 20	V
Continuous Drain Current ^c	I_{D}	8	-4.7	A
Pulsed Drain Current ^b	I_{DM}	32	-18	A
Power Dissipation ^c	P_{D}	2	2	W
Operation junction temperature	T_{J}	-55 to 150	-55 to 150	$^{\circ}\text{C}$
Storage temperature range	T_{STG}	-55 to 150	-55 to 150	$^{\circ}\text{C}$

➤ **Thermal Resistance Ratings ($T_A=25^{\circ}\text{C}$ unless otherwise noted)**

Symbol	Parameter	Channel	Ratings	Unit
$R_{\theta\text{JA}}$	Junction-to-Ambient Thermal Resistance ^a	N-Channel	62	$^{\circ}\text{C}/\text{W}$
$R_{\theta\text{JA}}$	Junction-to-Ambient Thermal Resistance ^a	P-Channel	62	

Note:

- The value of $R_{\theta\text{JA}}$ is measured with the device mounted on 1 in² FR-4 board with 2oz.copper, in a still air environment with $T_A=25^{\circ}\text{C}$. The value in any given application depends on the user's specific board design. The current rating is based on the $t \leq 10\text{s}$ thermal resistance rating.
- Repetitive rating, pulse width limited by junction temperature.
- The power dissipation P_{D} is based on $T_{\text{J(MAX)}}=150^{\circ}\text{C}$, using junction-to-case thermal resistance, and is more useful in setting the upper dissipation limit for cases where additional heat sinking is used.

**➤ N-Channel Electrical Characteristics ($T_A=25^{\circ}\text{C}$ unless otherwise noted)**

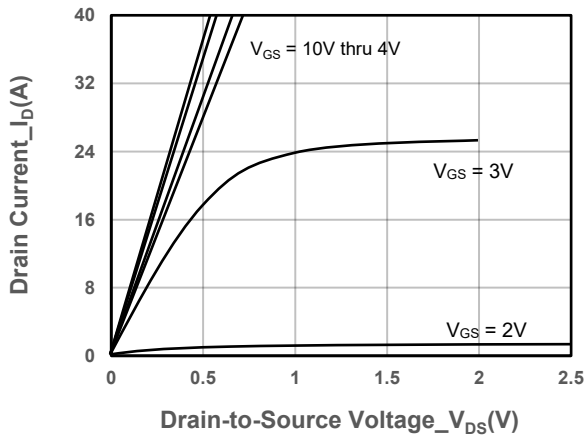
Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 250\mu A$	40			V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu A$	1	1.5	2.5	V
Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS} = 10V, I_D = 5.8A$		21	33	m Ω
		$V_{GS} = 4.5V, I_D = 5A$		27	38	
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 40V, V_{GS} = 0V$			1	μA
Gate-Source Leak Current	I_{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$			± 100	nA
Forward Voltage	V_{SD}	$V_{GS} = 0V, I_S = 2A$			1.3	V
Input Capacitance	C_{ISS}	$V_{DS} = 20V, V_{GS} = 0V,$ $f = 1MHz$		648		pF
Output Capacitance	C_{OSS}			55		
Reverse Transfer Capacitance	C_{RSS}			42		
Total Gate Charge	Q_G	$V_{GS} = 10V, V_{DS} = 20V,$ $I_D = 4A$		12		nC
Gate to Source Charge	Q_{GS}			2		
Gate to Drain Charge	Q_{GD}			2.3		
Turn-on Delay Time	$T_{D(ON)}$	$V_{GS} = 10V, V_{DS} = 20V,$ $R_L = 2.5\Omega, R_{GEN} = 3\Omega,$		14		ns
Rise Time	T_r			46		
Turn-off Delay Time	$T_{D(OFF)}$			20		
Fall Time	T_f			11		

➤ P-Channel Electrical Characteristics ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

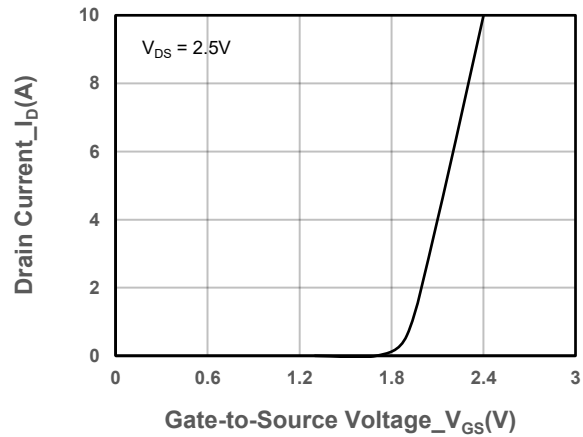
Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = -250\mu A$	-40			V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250\mu A$	-1	-1.5	-2.5	V
Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS} = -10V, I_D = -3.2A$		60	78	m Ω
		$V_{GS} = -4.5V, I_D = -2A$		70	95	
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = -40V, V_{GS} = 0V$			-1	μA
Gate-Source Leak Current	I_{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$			± 100	nA
Transconductance	G_{FS}	$V_{DS} = -10V, I_D = -4A$		5		s
Forward Voltage	V_{SD}	$V_{GS} = 0V, I_S = -2A$			-1.3	V
Input Capacitance	C_{ISS}	$V_{DS} = -20V, V_{GS} = 0V,$ $f = 1MHz$		540		pF
Output Capacitance	C_{OSS}			50		
Reverse Transfer Capacitance	C_{RSS}			41		
Total Gate Charge	Q_G	$V_{GS} = -20V, V_{DS} = -10V,$ $I_D = -5A$		14		nC
Gate to Source Charge	Q_{GS}			2.8		
Gate to Drain Charge	Q_{GD}			3.6		
Turn-on Delay Time	$T_{D(ON)}$	$V_{GS} = -10V, V_{DS} = -20V,$ $R_L = 2\Omega, R_G = 3\Omega$		9.5		ns
Rise Time	T_r			8		
Turn-off Delay Time	$T_{D(OFF)}$			27		
Fall Time	T_f			9		



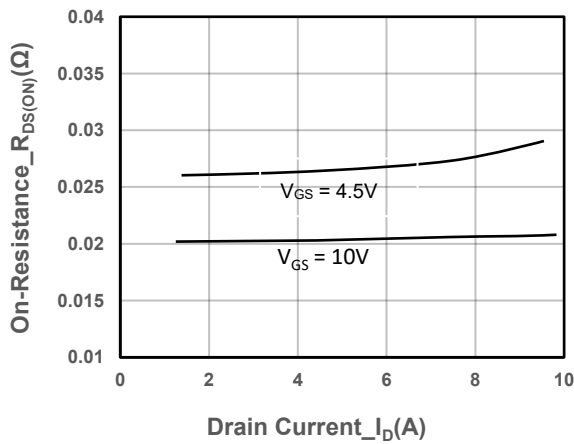
➤ N-Channel Typical Performance Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)



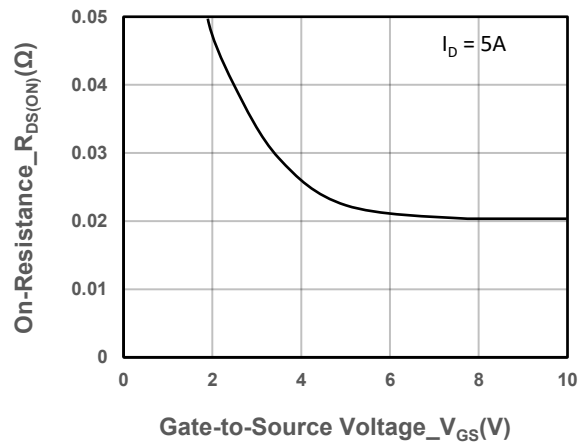
Output Characteristics



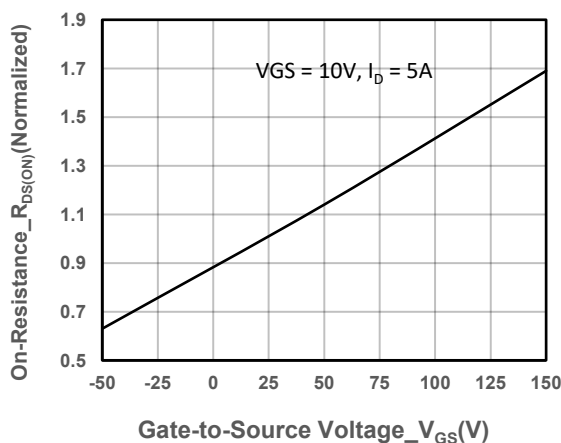
Transfer Characteristics



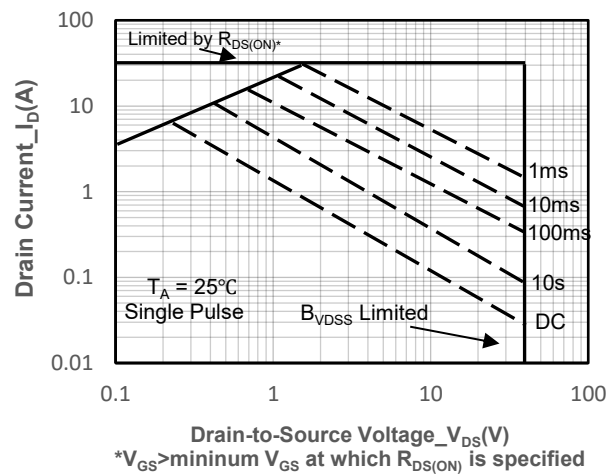
On-Resistance vs. Drain Current and Gate Voltage



On-Resistance vs. Gate-to-Source Voltage



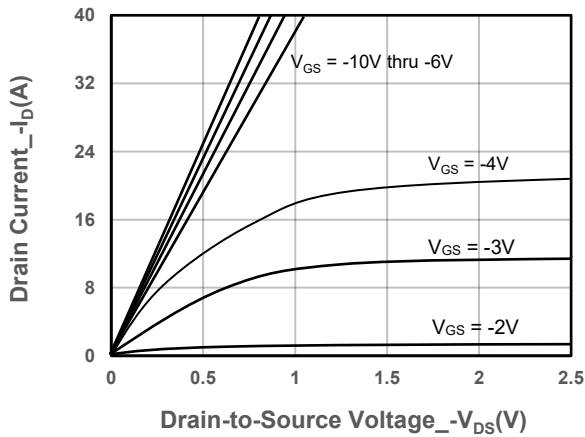
On-Resistance vs. Junction Temperature



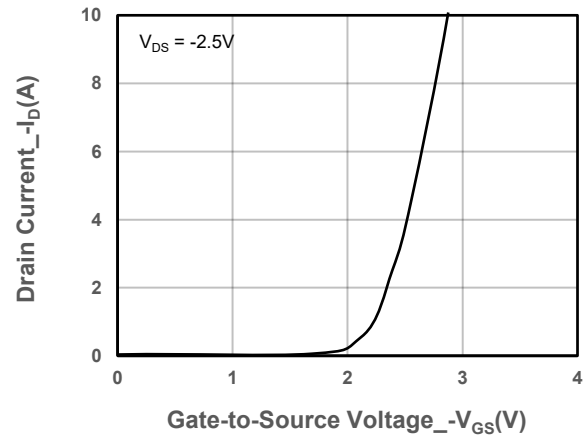
Safe Operating Area vs. Junction-to-Ambient



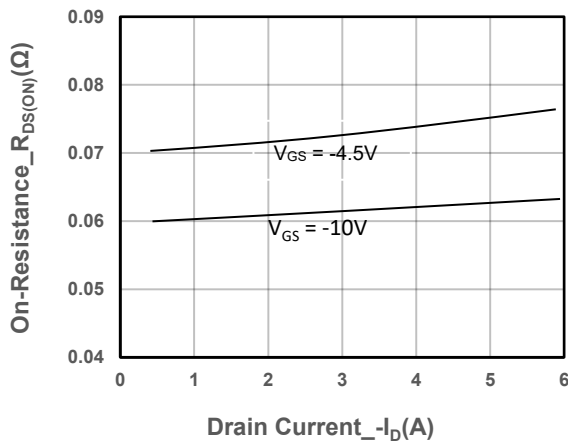
➤ P-Channel Typical Performance Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)



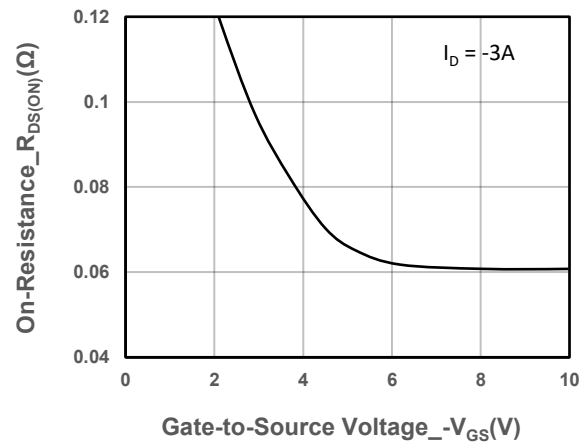
Output Characteristics



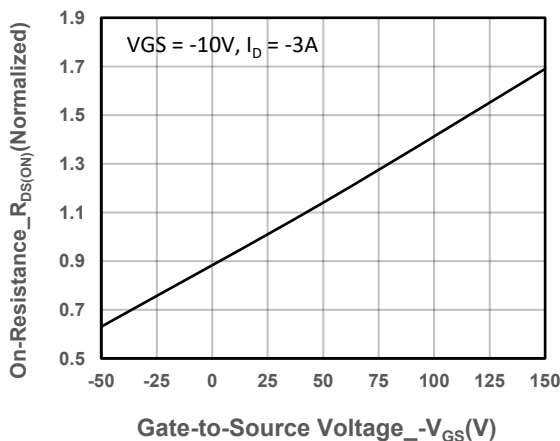
Transfer Characteristics



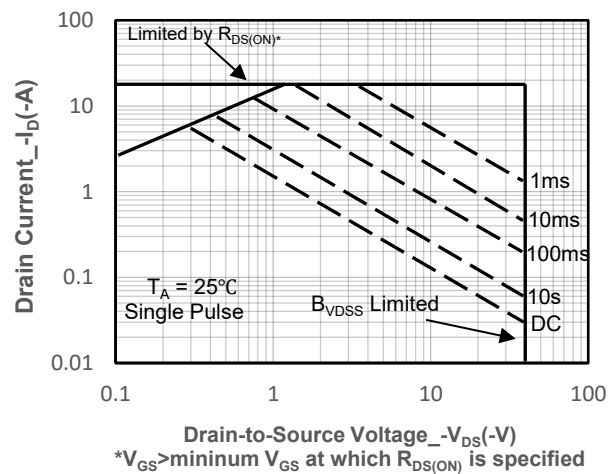
On-Resistance vs. Drain Current and Gate Voltage



On-Resistance vs. Gate-to-Source Voltage

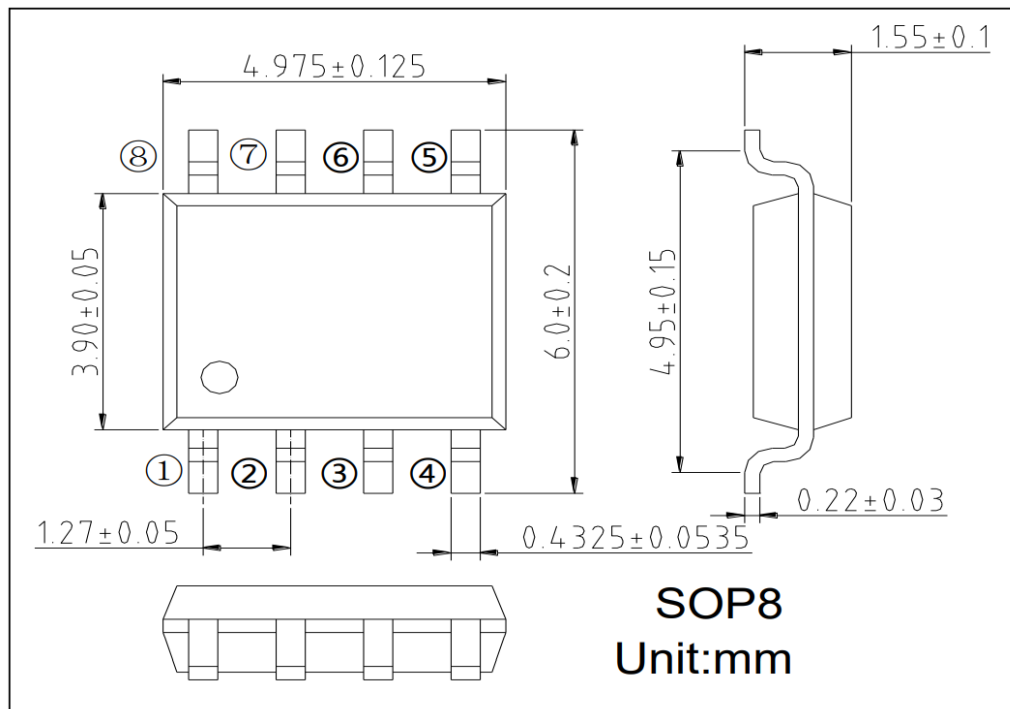


On-Resistance vs. Junction Temperature



Safe Operating Area vs. Junction-to-Ambient

➤ Package Information



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